

OC26 Transistors

Ge PNP Power BJT

Military/High-Rel N

$V_{(BR)CEO}$ (V) 35

$V_{(BR)CBO}$ (V) 32

I_C Max. (A) 3.5

Absolute Max. Power Diss. (W) 13

Maximum Operating Temp ($^{\circ}C$) 100 \bar{o}

I_{CBO} Max. (A) 20m \bar{o}

@ V_{CBO} (V) (Test Condition)

$V_{(CE)sat}$ Max. (V)

@ I_C (A) (Test Condition)

@ I_B (A) (Test Condition)

$h_{(FE)}$ Min. Current gain. 20

$h_{(FE)}$ Max. Current gain. 60

@ I_C (A) (Test Condition) 1.0

@ $V_{(CE)}$ (V) (Test Condition) 1.0

f_T Min. (Hz) Transition Freq 150k \bar{i}

@ I_C (A) (Test Condition)

@ $V_{(CE)}$ (V) (Test Condition)

t_r Max. (s) Rise time

t_f Max. (s) Fall time.

Package Style TO-3